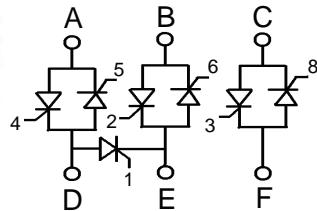


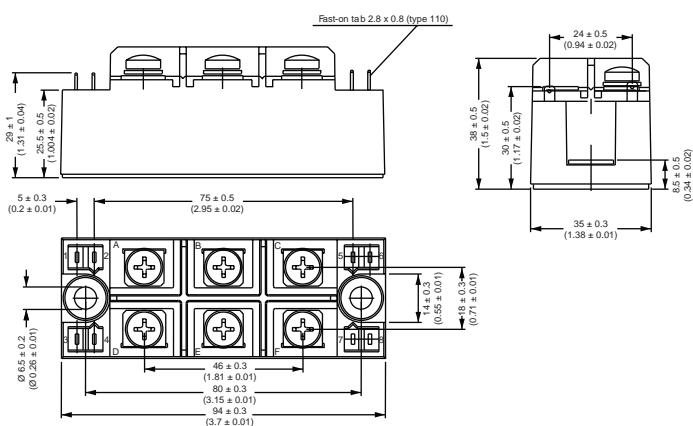
S3SSAC70G16TB

Three Phase Solid State AC Switch Modules



Type	V_{RSM} V	V_{RRM} V
S3SSAC70G08TB	900	800
S3SSAC70G12TB	1300	1200
S3SSAC70G16TB	1700	1600
S3SSAC70G18TB	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS}	$T_{VJ}=T_{VJM}$	110	
I_{TAVM}	$T_c=85^\circ\text{C}$; 180° sine	70	A
I_{TSM}	$T_{VJ}=45^\circ\text{C}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	1280	A
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	1350	
I^2t	$T_{VJ}=45^\circ\text{C}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	7500	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	8100	
$(di/dt)_{cr}$	$T_{VJ}=125^\circ\text{C}$ $f=50\text{Hz}$, $t_p=200\mu\text{s}$ $V_D=2/3V_{DRM}$ $I_G=0.3\text{A}$ $diG/dt=0.3\text{A}/\mu\text{s}$	1150	$\text{A}/\mu\text{s}$
	repetitive, $I_T=250\text{A}$ non repetitive, $I_T=I_{TAVM}$	1230	
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $R_{GK}=\infty$; method 1 (linear voltage rise)	5600	$\text{V}/\mu\text{s}$
	$V_{DR}=2/3V_{DRM}$	5250	
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$ $t_p=30\mu\text{s}$	150	W
	$t_p=300\mu\text{s}$	1000	
	$t_p = 10\text{ms}$	500	
T_{VJ} T_{VJM} T_{stg}		-40...+125	$^\circ\text{C}$
		125	
		-40...+125	
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq 1\text{mA}$	2500	$\text{V}\sim$
	$t=1\text{min}$ $t=1\text{s}$	3000	
M_d	Mounting torque (M5) (10-32 UNF)	$5 \pm 15 \%$ $44 \pm 15 \%$	Nm/lb.in.
		250	
Weight			g

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S3SSAC70G16TB

Three Phase Solid State AC Switch Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_D, I_R	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	5	mA
V_T, V_F	$I_T, I_F=210A; T_{VJ}=25^\circ C$	1.65	V
V_{TO}	For power-loss calculations only	0.85	V
r_T		3.2	$m\Omega$
V_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	1.5 1.6	V
I_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	100 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; $V_D=2/3V_{DRM}$	0.2	V
I_{GD}		5	mA
I_L	$T_{VJ}=25^\circ C$; $t_p=10\mu s$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	450	mA
I_H	$T_{VJ}=25^\circ C$; $V_D=6V$; $R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^\circ C$; $V_D=1/2V_{DRM}$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	2	us
t_q	$T_{VJ}=T_{VJM}$; $I_T=20A$; $t_p=200\mu s$; $-dI/dt=10A/\mu s$ $V_R=100V$; $dv/dt=15V/\mu s$; $V_D=2/3V_{DRM}$	typ. 185	us
I_{RM}		45	A
R_{thJC}	per thyristor/diode; DC current per module	0.42 0.07	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.62 0.11	K/W
ds	Creeping distance on surface	12.5	mm
da	Strike distance through air	7.5	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES

- Thyristor controller for AC for mains frequency
- Isolation voltage 3000 VAC
- Package with metal base plate

APPLICATIONS

- ! Switching and control of three phase AC circuits
- \$ Light and temperature control
- % Softstart AC motor controller
- 4. Solid state switches

ADVANTAGES

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density

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Three Phase Solid State AC Switch Modules

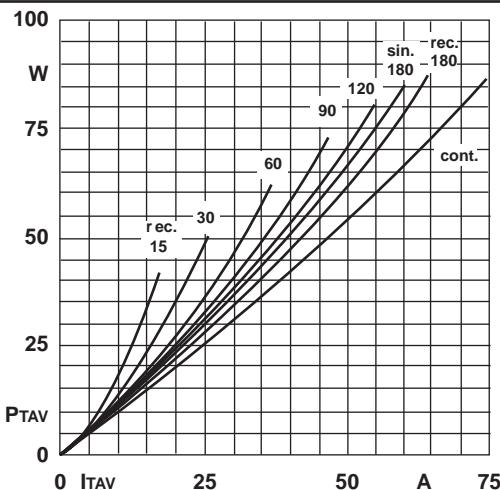


Fig.1L Power dissipation per thyristor vs. on-state current

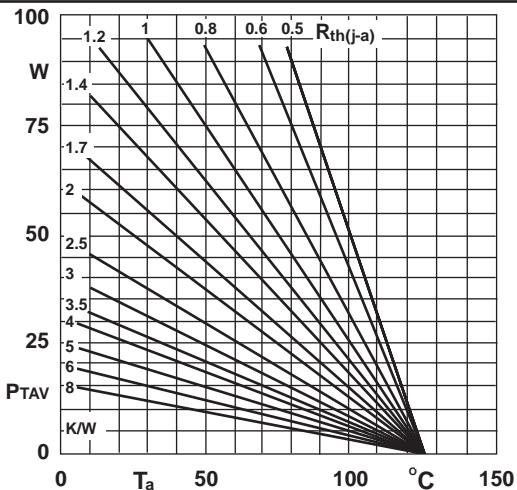


Fig.1R Power dissipation per thyristor vs. ambient temp

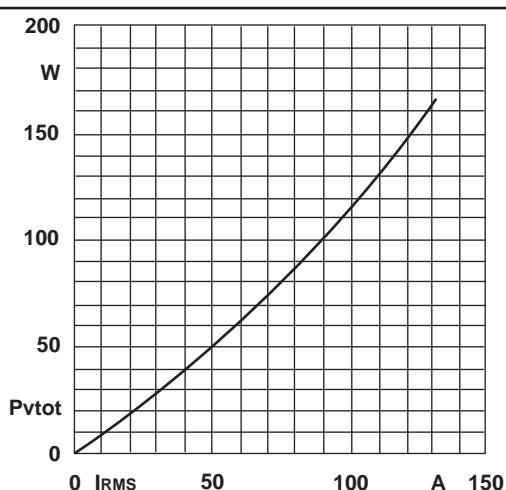


Fig.2L Power dissipation per module vs. rms current

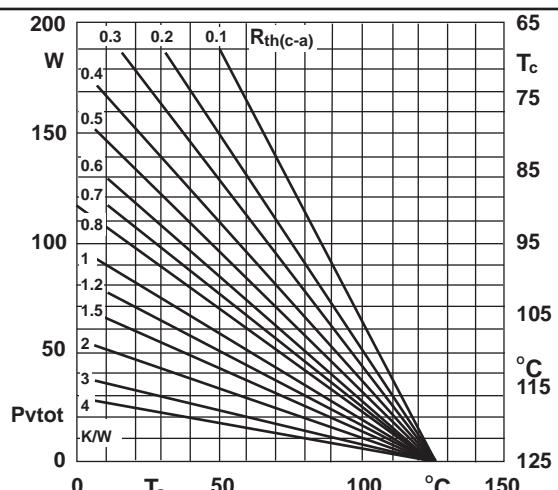


Fig.2R Power dissipation per module vs. case temp

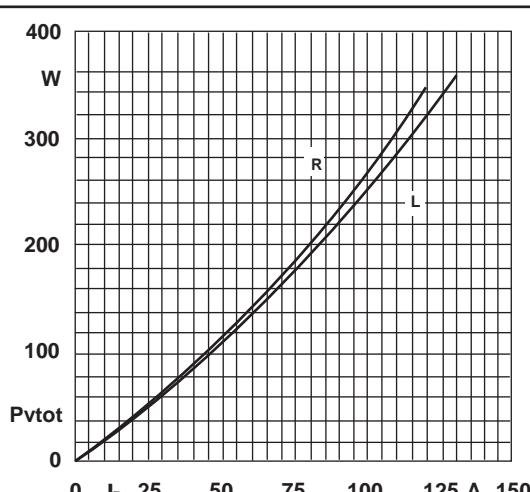


Fig.3L Power dissipation of two modules vs. direct current

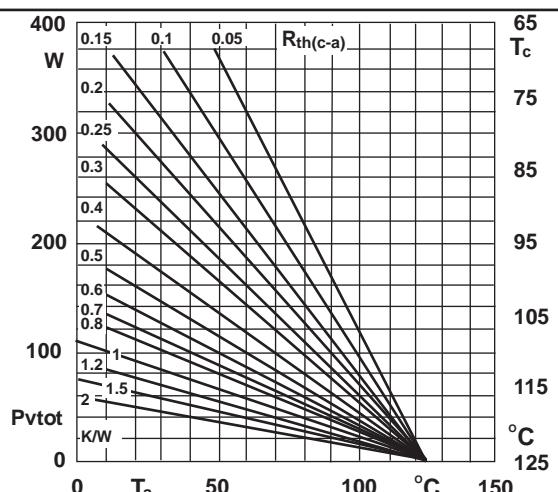


Fig.3R Power dissipation of two modules vs. case temp

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Three Phase Solid State AC Switch Modules

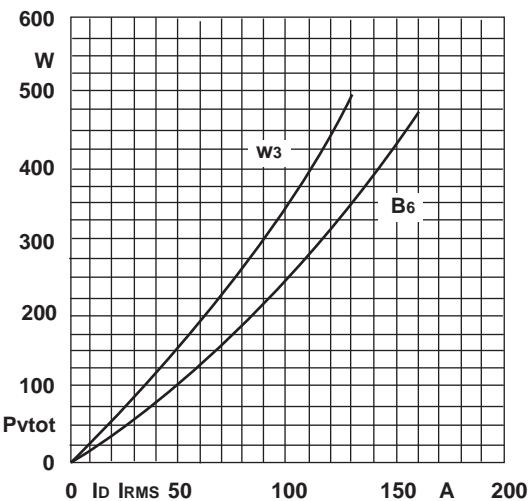


Fig.4L Power dissipation of three modules vs. direct and rms current

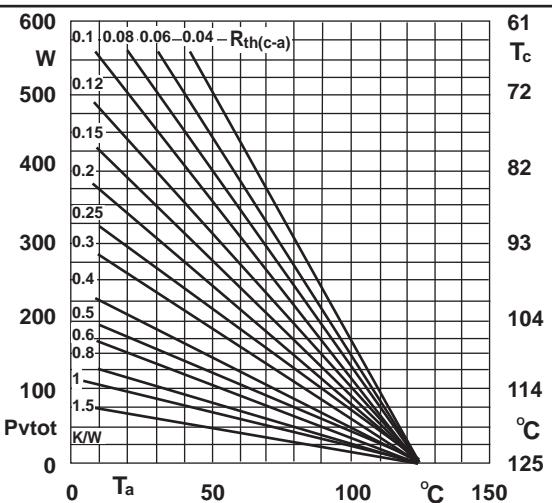


Fig.4R Power dissipation of three modules vs. case temp

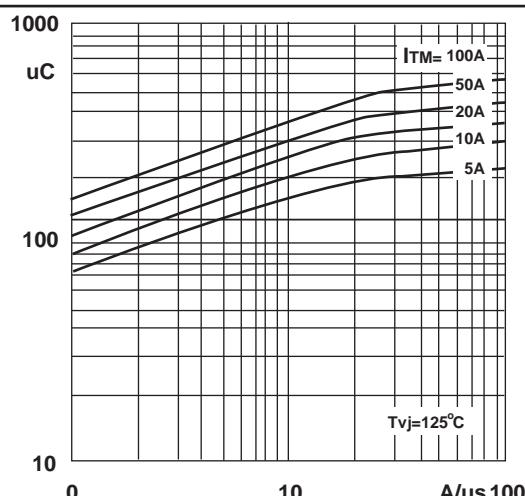


Fig.5 Recovered charge vs. current decrease

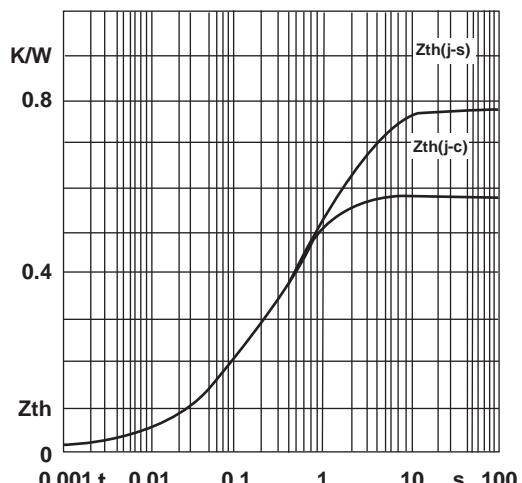


Fig.6 Transient thermal impedance vs. time

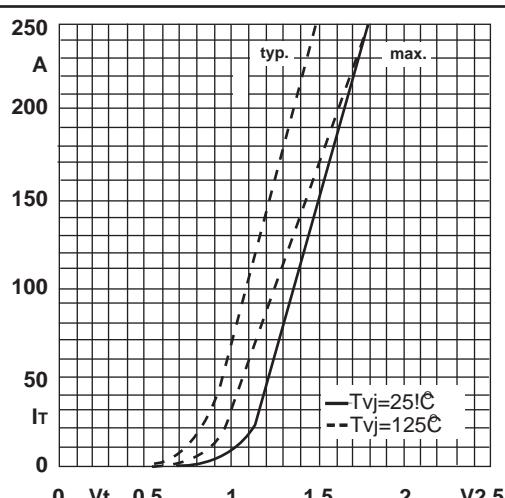


Fig.7 On-state characteristics

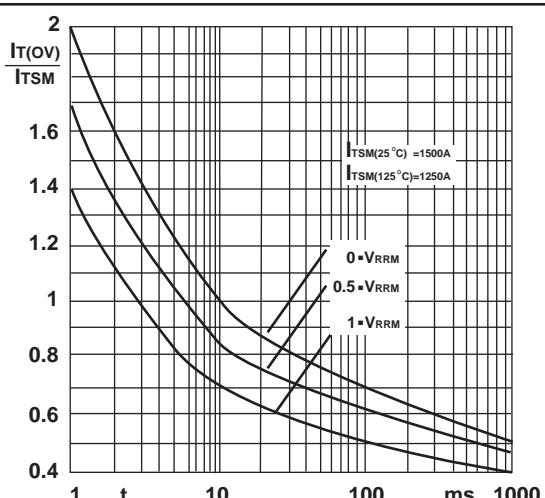


Fig.8 Surge overload current vs. time